NSN 5961-01-004-1056

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-004-1056 **Inclosure Material:** Metal **Overall Length:** Between 0.560 inches and 0.625 inches **Overall Height:** Between 0.140 inches and 0.190 inches Overall Width: Between 0.380 inches and 0.420 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 45.0 breakdown voltage, collector-to-base, emitter open and 40.0 breakdown voltage, collector-to-emitter, base open and 5.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** Between 4.00 amperes source cutoff current and 16.00 amperes source cutoff current **Power Rating Per Characteristic:** 75.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 165.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: No